

isc N-Channel MOSFET Transistor

TK62N60X

FEATURES

- Low drain-source on-resistance:
 R_Ds(on) ≤40mΩ.
- Enhancement mode:
 Vth =2.5 to 3.5V (VDS = 10 V, ID=3.1mA)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

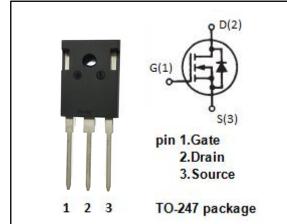
Switching Voltage Regulators

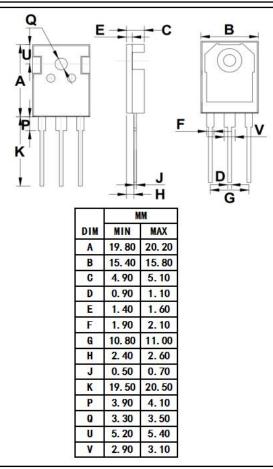
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|-------------------------------------|---------|--------------|--|
| V_{DSS} | Drain-Source Voltage | 600 | V | |
| V _{GS} | Gate-Source Voltage | ±30 | V | |
| I _D | Drain Current-Continuous | 61.8 | А | |
| I _{DM} | Drain Current-Single Pulsed | 247 | А | |
| P _D | Total Dissipation @Tc=25℃ | 400 | W | |
| Tj | Max. Operating Junction Temperature | 150 | $^{\circ}$ | |
| T _{stg} | Storage Temperature | -55~150 | $^{\circ}$ C | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|------------------------------------|-------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 0.313 | °C/W |







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | МАХ | UNIT |
|---------------------|--------------------------------|---|-----|-----|-----|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D =10mA | 600 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =10V; I _D =3.1mA | 2.5 | | 3.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =21A | | | 40 | mΩ |
| lgss | Gate-Source Leakage Current | V _{GS} = ±30V;V _{DS} = 0V | | | ±1 | μА |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =600V; V _{GS} = 0V | | | 10 | uA |
| V _{SDF} | Diode forward voltage | I _{DR} =61.8A, V _{GS} = 0 V | | | 1.7 | V |



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